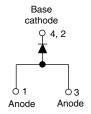


Schottky Rectifier, 10 A



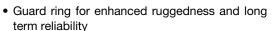


D-PA	V/7	\sim	E2 A	A \
D-FA	ווא	U-2	32 A	Αı

PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I _{F(AV)}	10 A					
V_R	45 V					
V _F at I _F	0.53 V					
I _{RM}	15 mA at 125 °C					
T _J max.	175 °C					
Diode variation	Single die					
E _{AS}	20 mJ					

FEATURES

• Low forward voltage drop





• Halogen-free according to IEC 61249-2-21 definition

- FREE
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-10WQ045FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	10	А						
V _{RRM}		45	V						
I _{FSM}	t _p = 5 µs sine	400	А						
V _F	10 Apk, T _J = 125 °C	0.53	V						
T _J	Range	- 40 to 175	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-10WQ045FN-M3	UNITS					
Maximum DC reverse voltage	V _R	45	V					
Maximum working peak reverse voltage	V_{RWM}	45						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 157 °C	10	А				
Maximum peak one cycle non-repetitive surge current	o po onto or o porto a parce		Following any rated	400	А			
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	75	7			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH		20	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		3.0	А			

Schottky Rectifier, 10 A



Document Number: 93284

Revision: 03-Nov-10

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
		10 A	T _{.1} = 25 °C	0.63	V			
Maximum forward voltage drop	V _{EM} (1)	20 A	11 = 23 0	0.80				
See fig. 1	VFM (1)	10 A	T 105 %C	0.53				
		20 A	- T _J = 125 °C	0.71				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	1	· mA			
See fig. 2	'RM (*)	T _J = 125 °C	VR = nateu VR	15				
Threshold voltage	V _{F(TO)}	T - T maximum		0.255	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum		22	mΩ			
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	760	pF				
Typical series inductance	L _S	Measured lead to lead 5 i	mm from package body	5.0	nH			

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,\,duty\,cycle < 2~\%$

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 175	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	2.0	°C/W				
Maximum thermal resistance, junction to ambient	R _{thJA}		50	G/VV				
Approximate weight			0.3	g				
Approximate weight			0.01	OZ.				
Marking device		Case style D-PAK (similar to TO-252AA)	10WQ	045FN				

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$



Schottky Rectifier, 10 A

Vishay Semiconductors

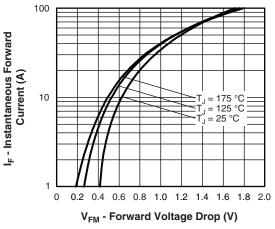


Fig. 1 - Maximum Forward Voltage Drop Characteristics

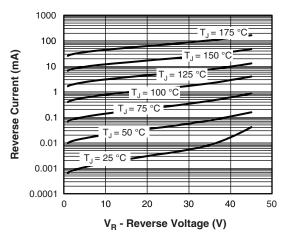


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

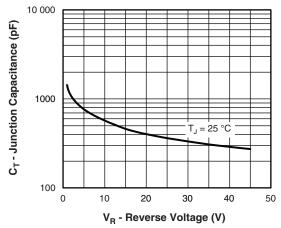


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

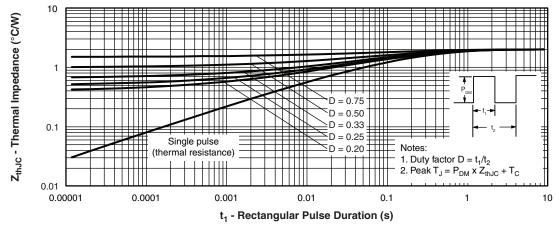


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Schottky Rectifier, 10 A



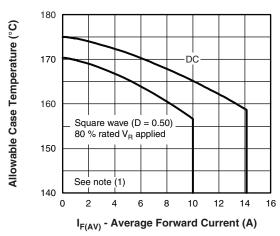


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

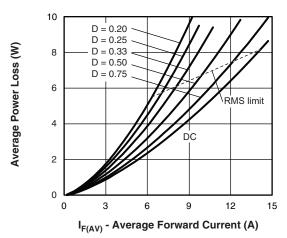


Fig. 6 - Forward Power Loss Characteristics

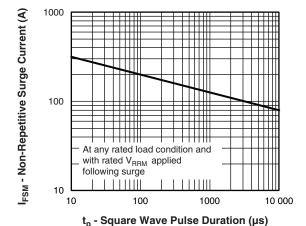


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

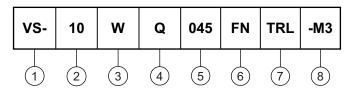


Schottky Rectifier, 10 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (045 = 45 V)

6 - FN = TO-252AA (D-PAK)

7 - • None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-10WQ045FN-M3	75	3000	Antistatic plastic tube					
VS-10WQ045FNTR-M3	2000	2000	13" diameter reel					
VS-10WQ045FNTRL-M3	3000	3000	13" diameter reel					
VS-10WQ045FNTRR-M3	3000	3000	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95016				
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				



NOTES

3

2

MAX.

0.410

0.070

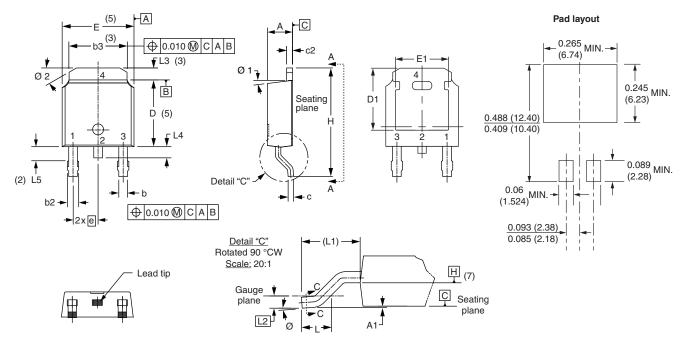
0.050

0.040

0.060

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



Ī	SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		
		MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX
ſ	Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC
ſ	A1	-	0.13		0.005			Н	9.40	10.41	0.370	0.41
Ī	b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.07
Ī	b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.
ſ	b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC
Ī	С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.05
Ī	c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.04
ſ	D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.06
Ī	D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°
ſ	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°
Ī	E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



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